TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC175AP,TC74HC175AF,TC74HC175AFN

Quad D-Type Flip Flop with Clear

The TC74HC175A is a high speed CMOS D-TYPE FLIP FLOP fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q and \overline{Q} outputs on the positive going edge of the clock pulse.

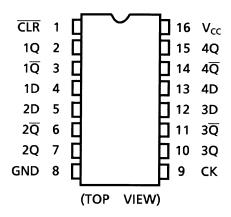
When the \overline{CLR} input is held low, the Q outputs are at the low logic level and the \overline{Q} outputs are at the high logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

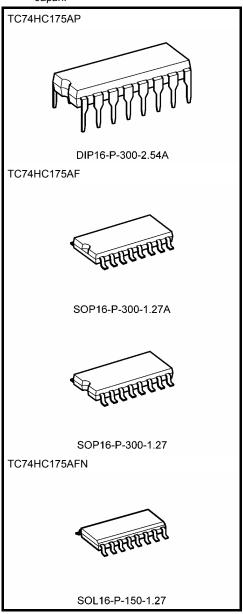
Features

- High speed: $f_{max} = 63 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{\rm CC}$ = 4 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 74LS175

Pin Assignment



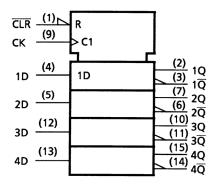
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOP16-P-300-1.27 : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

IEC Logic Symbol

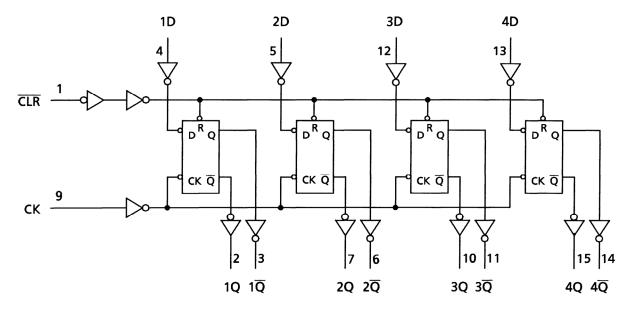


Truth Table

	Inputs		Out	puts	Function		
CLR	D	CK	Q	Q	Function		
L	Х	Х	L	Н	Clear		
Н	L	\Box	L	Н	_		
Н	Н		Н	L	_		
Н	Х	\neg	Qn	\overline{Q}_n	No Change		

X: Don't care

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	٧
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		_	-	Ta = 25°(Ta = -40 to 85°C		Unit
	,			V _{CC} (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}	_		4.5	3.15	_	_	3.15	_	V
				6.0	4.20		_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_		1.35	_	1.35	V
ŭ			-	6.0			1.80		1.80	
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ü			I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
Ü			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0		_	±0.1		±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	6.0	_	_	4.0		40.0	μА



Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	*		2.0	_	75	95	
·	t _{W (L)}	_	4.5	_	15	19	ns
(CK)	t _{W (H)}		6.0	_	13	16	
Minimum nula a width			2.0	_	75	95	
Minimum pulse width (CLR)	t _{W (L)}	_	4.5	_	15	19	ns
(CLR)			6.0		13	16	
			2.0		75	95	
Minimum set-up time	t _s	_	4.5	_	15	19	ns
			6.0	_	13	16	
			2.0		0	0	
Minimum hold time	t _h	_	4.5	_	0	0	ns
			6.0	_	0	0	
			2.0		75	95	
Minimum removal time	t _{rem}	_	4.5	_	15	19	ns
			6.0		13	16	
			2.0	_	6	5	
Clock frequency	f	_	4.5	_	31	25	MHz
			6.0	_	36	29	

AC Characteristics (C $_L$ = 15 pF, V_{CC} = 5 V, Ta = 25 $^{\circ}\text{C},$ input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition		Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	4	8	ns
	t _{THL}					110
Propagation delay time	t _{pLH}		_	16	24	ns
$(CK-Q, \overline{Q})$	t_{pHL}	_				115
Propagation delay time	t _{pLH}			13	21	20
$(\overline{CLR}-Q,\ \overline{Q})$	t_{pHL}	_	_	13	<u> </u>	ns
Maximum clock frequency	f _{max}	_	36	63	_	MHz



AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
	4		2.0	_	30	75	_	95	
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns
	t _{THL}		6.0	_	7	13	_	16	
Dranagation delay time	4		2.0	_	70	140	_	175	
Propagation delay time	t _{pLH}	_	4.5	_	19	28	_	35	ns
(CK-Q, Q)	t _{pHL}		6.0	_	16	24	_	30	
Drangastian dalay time	4		2.0	_	50	125	_	160	
Propagation delay time	t _{pLH}	_	4.5	_	16	25	_	32	ns
$(\overline{CLR}-Q,\ \overline{Q})$	t_{pHL}		6.0	_	12	22	_	27	
			2.0	6	14	_	5	_	
Maximum clock frequency	f _{max}	_	4.5	31	53	_	25	_	MHz
			6.0	36	63	_	29	_	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	53	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

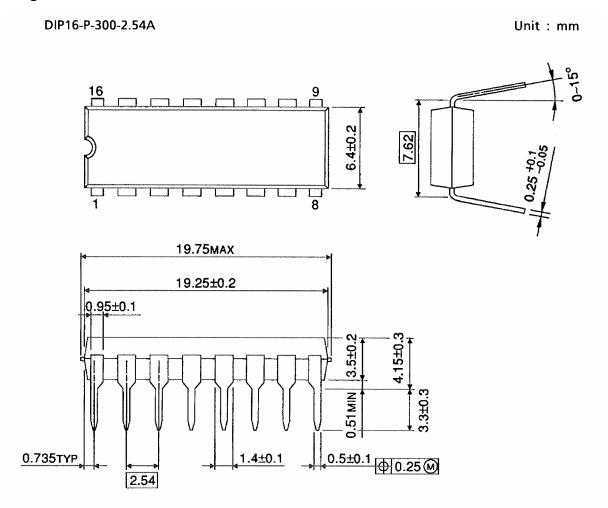
Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per F/F)

And the total CPD when n pcs. of Flip Flop operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 32 + 21 · n

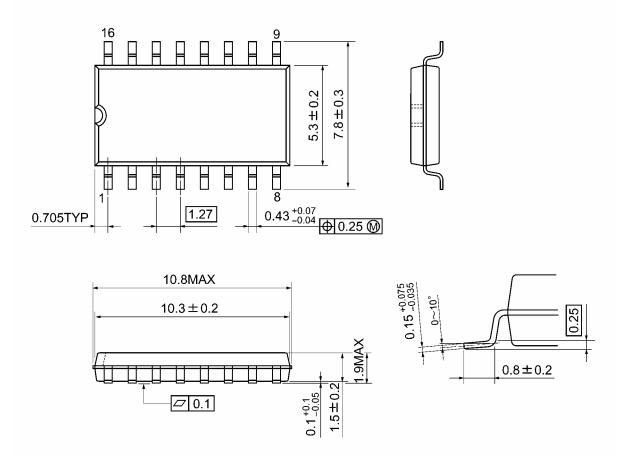
Package Dimensions



Weight: 1.00 g (typ.)

Package Dimensions

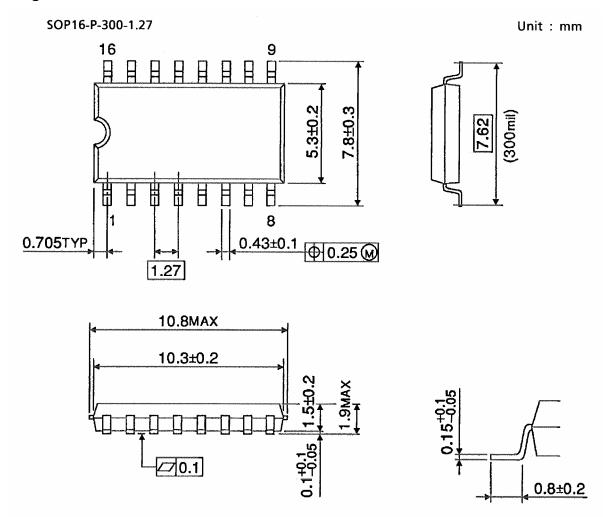
SOP16-P-300-1.27A Unit: mm



8

Weight: 0.18 g (typ.)

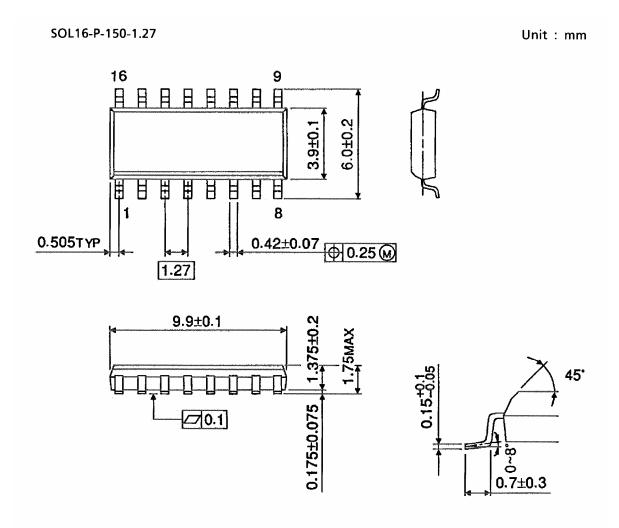
Package Dimensions



Weight: 0.18 g (typ.)



Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27

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